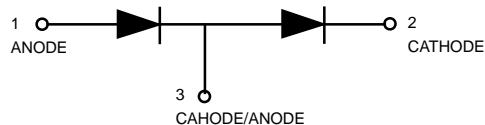


Dual Series Switching Diode

LBAV99LT1

DEVICE MARKING

LBAV99LT1 = A7

MAXIMUM RATINGS (EACH DIODE)

Rating	Symbol	Value	Unit
Reverse Voltage	V_R	70	Vdc
Forward Current	I_F	215	mAdc
Peak Forward Surge Current	$I_{FM(surge)}$	500	mAdc
Repetitive Peak Reverse Voltage	V_{RRM}	70	V
Average Rectified Forward Current (1) (averaged over any 20 ms period)	$I_{F(AV)}$	715	mA
Repetitive Peak Forward Current	I_{FRM}	450	mA
Non-Repetitive Peak Forward Current $t = 1.0 \mu s$	I_{FSM}	2.0	
$t = 1.0 \text{ ms}$		1.0	
$t = 1.0 \text{ S}$		0.5	


SOT-23
THERMAL CHARACTERISTICS

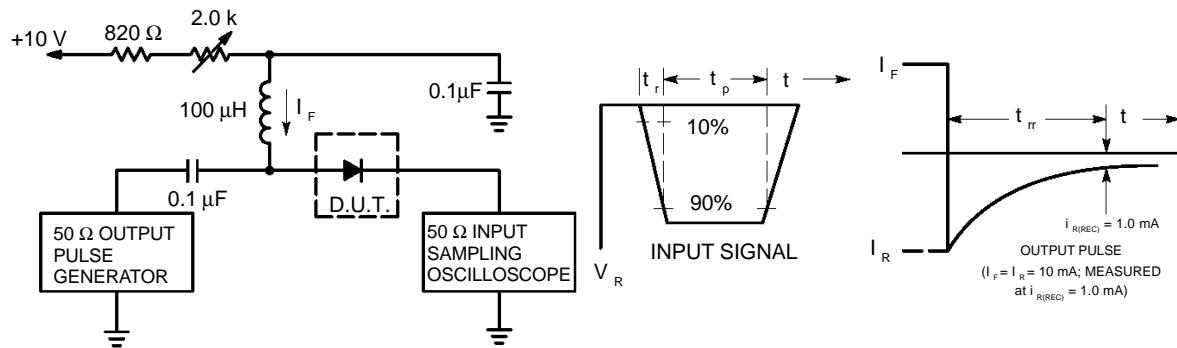
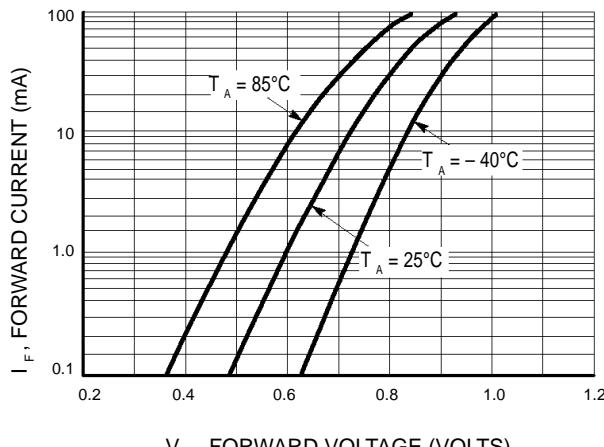
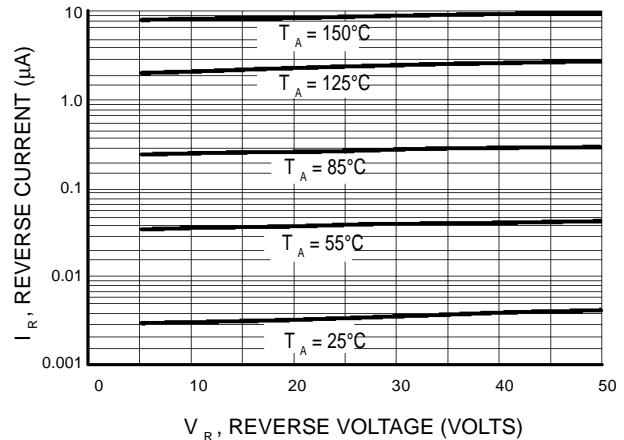
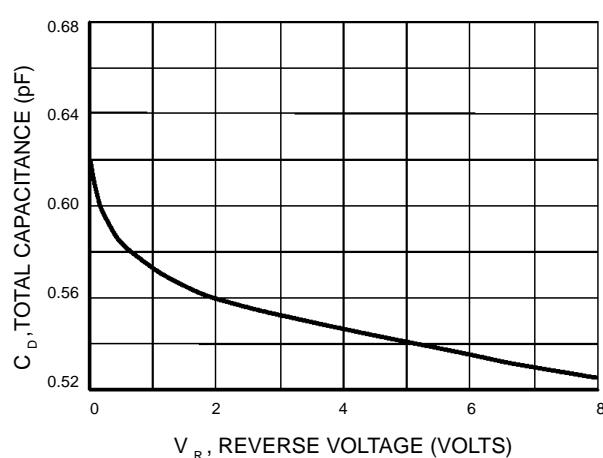
Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board, (1) $T_A = 25^\circ\text{C}$	P_D	225	mW
Derate above 25°C		1.8	mW/ $^\circ\text{C}$
Thermal Resistance Junction to Ambient	$R_{\theta JA}$	556	$^\circ\text{C}/\text{W}$
Total Device Dissipation Alumina Substrate, (2) $T_A = 25^\circ\text{C}$	P_D	300	mW
Derate above 25°C		2.4	mW/ $^\circ\text{C}$
Thermal Resistance Junction to Ambient	$R_{\theta JA}$	417	$^\circ\text{C}/\text{W}$
Junction and Storage Temperature	T_J, T_{sig}	-65 to +150	$^\circ\text{C}$

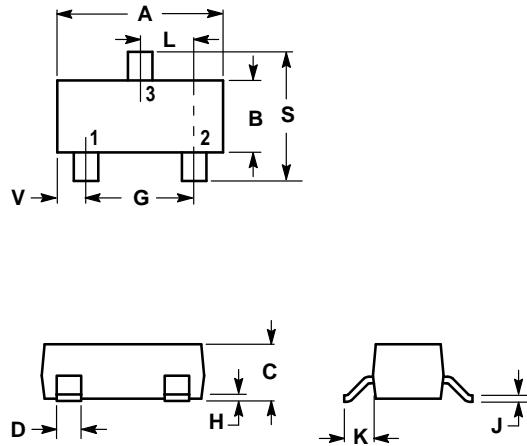
ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted) (EACH DIODE)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Reverse Breakdown Voltage($I_{(BR)} = 100 \mu\text{A}$)	$V_{(BR)}$	70	—	Vdc
Reverse Voltage Leakage Current ($V_R = 70 \text{ Vdc}$)	I_R	—	2.5	μAdc
($V_R = 25 \text{ Vdc}, T_J = 150^\circ\text{C}$)		—	30	
($V_R = 70 \text{ Vdc}, T_J = 150^\circ\text{C}$)		—	50	
Diode Capacitance ($V_R = 0, f = 1.0 \text{ MHz}$)	C_D	—	1.5	pF
Forward Voltage ($I_F = 1.0 \text{ mAdc}$)	V_F	—	715	mVdc
($I_F = 10 \text{ mAdc}$)		—	855	
($I_F = 50 \text{ mAdc}$)		—	1000	
($I_F = 150 \text{ mAdc}$)		—	1250	
Reverse Recovery Time ($I_F = I_R = 10 \text{ mAdc}, i_{R(REO)} = 1.0 \text{ mAdc}, R_L = 100\Omega$) (Figure 1)	t_{rr}	—	6.0	ns
Forward Recovery Voltage ($I_F = 10 \text{ mA}, t_r = 20 \text{ ns}$)	V_{FR}	—	1.75	V

1. FR-5 = $1.0 \times 0.75 \times 0.062 \text{ in.}$

2. Alumina = $0.4 \times 0.3 \times 0.024 \text{ in. } 99.5\% \text{ alumina.}$

LBAV99LT1

Figure 1. Recovery Time Equivalent Test Circuit
CURVES APPLICABLE TO EACH DIODE

Figure 2. Forward Voltage

Figure 3. Leakage Current

Figure 4. Capacitance

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NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.1102	0.1197	2.80	3.04
B	0.0472	0.0551	1.20	1.40
C	0.0350	0.0440	0.89	1.11
D	0.0150	0.0200	0.37	0.50
G	0.0701	0.0807	1.78	2.04
H	0.0005	0.0040	0.013	0.100
J	0.0034	0.0070	0.085	0.177
K	0.0140	0.0285	0.35	0.69
L	0.0350	0.0401	0.89	1.02
S	0.0830	0.1039	2.10	2.64
V	0.0177	0.0236	0.45	0.60

PIN 1. ANODE
 2. CAHODE
 3. CAHODE/ANODE

